

Single Inverter

MC74HC1G04

The MC74HC1G04 is a high speed CMOS inverter fabricated with silicon gate CMOS technology.

The internal circuit is composed of multiple stages, including a buffer output which provides high noise immunity and stable output.

The MC74HC1G04 output drive current is 1/2 compared to MC74HC series.

Features

- High Speed: $t_{PD} = 7 \text{ ns (Typ)}$ at $V_{CC} = 5 \text{ V}$
- Low Power Dissipation: $I_{CC} = 1 \mu A$ (Max) at $T_A = 25^{\circ}C$
- High Noise Immunity
- Balanced Propagation Delays $(t_{pLH} = t_{pHL})$
- Symmetrical Output Impedance ($I_{OH} = I_{OL} = 2 \text{ mA}$)
- Chip Complexity: < 100 FETs
- –Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

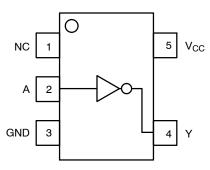


Figure 1. Pinout



Figure 2. Logic Symbol

| PIN ASSIGNMENT | | | | |
|----------------|-----------------|--|--|--|
| 1 | NC | | | |
| 2 | А | | | |
| 3 | GND | | | |
| 4 | Υ | | | |
| 5 | V _{CC} | | | |

MARKING DIAGRAMS



SC-88A DF SUFFIX CASE 419A





SC-74A DBV SUFFIX CASE 318BQ



XXX = Specific Device Code

M = Date Code

■ = Pb-Free Package

(Note: Microdot may be in either location)

FUNCTION TABLE

| Input A | Output Y |
|---------|----------|
| L | Н |
| Н | L |

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

MAXIMUM RATINGS

| Symbol | Parameter | | Value | Unit |
|-------------------------------------|---|--|------------------------------|------|
| V _{CC} | DC Supply Voltage | | -0.5 to +6.5 | V |
| V _{IN} | DC Input Voltage | | -0.5 to V _{CC} +0.5 | V |
| V _{OUT} | DC Output Voltage | | -0.5 to V _{CC} +0.5 | V |
| I _{IK} | DC Input Diode Current | | ±20 | mA |
| l _{ok} | DC Output Diode Current | | ±20 | mA |
| l _{out} | DC Output Source/Sink Current | | ±12.5 | mA |
| I _{CC} or I _{GND} | DC Supply Current per Supply Pin or Ground Pin | ±25 | mA | |
| T _{STG} | Storage Temperature Range | | -65 to +150 | °C |
| T _L | Lead Temperature, 1 mm from Case for 10 Seconds | | 260 | °C |
| T_J | Junction Temperature Under Bias | | +150 | °C |
| $\theta_{\sf JA}$ | Thermal Resistance (Note 1) | SC-88A SC-74A | 377 320 | °C/W |
| P _D | Power Dissipation in Still Air at 85°C | SC-88A SC-74A | 332 390 | mW |
| MSL | Moisture Sensitivity | | Level 1 | |
| F _R | Flammability Rating | Oxygen Index: 28 to 34 | UL 94 V-0 @ 0.125 in | |
| V _{ESD} | ESD Withstand Voltage (Note 2) | Human Body Model Charged Device Model | 2000 1000 | V |
| I _{LATCHUP} | Latchup Performance (Note 3) | | ±100 | mA |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 20 ounce copper trace with no air flow per JESD51-7.

2. HBM tested to ANSI/ESDA/JEDEC JS-001-2017. CDM tested to JESD22-C101-F. JEDEC recommends that ESD qualification to

- EIA/JESD22-A115A (Machine Model) be discontinued per JEDEC/JEP172A.
- 3. Tested to EIA/JESD78 Class II.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Min | Max | Unit |
|---------------------------------|--|------------------|---------------------|------|
| V _{CC} | DC Supply Voltage | 2.0 | 6.0 | V |
| V _{IN} | DC Input Voltage | 0.0 | V_{CC} | V |
| V _{OUT} | DC Output Voltage | 0.0 | V _{CC} | V |
| T _A | Operating Temperature Range | -55 | +125 | °C |
| t _r , t _f | Input Rise and Fall Time $V_{CC}=2.0\ V$ $V_{CC}=2.3\ V\ to\ 2.7\ V$ $V_{CC}=3.0\ V\ to\ 3.6\ V$ $V_{CC}=4.5\ V\ to\ 6.0\ V$ | 0 0 0 0 | 20 20 10 5 | ns/V |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

| | | | V _{CC} | Т | A = 25° | С | -40°C ≤ 1 | Γ _A ≤ 85°C | -55°C ≤ T | _A ≤ 125°C | |
|-----------------|------------------------------|---|--------------------------|----------------------------|--------------------------|----------------------------|----------------------------|----------------------------|----------------------------|----------------------------|------|
| Symbol | Parameter | Test Conditions | (V) | Min | Тур | Max | Min | Max | Min | Max | Unit |
| V _{IH} | High-Level Input Voltage | | 2.0 3.0 4.5 6.0 | 1.5 2.1 3.15 4.20 | - - - | | 1.5 2.1 3.15 4.20 | - - - | 1.5 2.1 3.15 4.20 | - - - | ٧ |
| V _{IL} | Low-Level Input Voltage | | 2.0 3.0 4.5 6.0 | - - - | - - - | 0.5 0.9 1.35 1.80 | - - - - | 0.5 0.9 1.35 1.80 | - - - - | 0.5 0.9 1.35 1.80 | V |
| V _{OH} | High-Level Output Voltage | $V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -20 \mu A$ | 2.0 3.0 4.5 6.0 | 1.9 2.9 4.4 5.9 | 2.0 3.0 4.5 6.0 | | 1.9 2.9 4.4 5.9 | - - - | 1.9 2.9 4.4 5.9 | - - - | V |
| | | $V_{IN} = V_{IH}$ or V_{IL} $I_{OH} = -2$ mA $I_{OH} = -2.6$ mA | 4.5 6.0 | 4.18 5.68 | 4.31 5.80 | 1 1 | 4.13 5.63 | - - | 4.08 5.58 | - - | |
| V _{OL} | Low-Level Output Voltage | $V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 20 \mu\text{A}$ | 2.0 3.0 4.5 6.0 | - - - | 0.0 0.0 0.0 0.0 | 0.1 0.1 0.1 0.1 | 1 1 1 1 | 0.1 0.1 0.1 0.1 | 1 1 | 0.1 0.1 0.1 0.1 | V |
| | | $V_{IN} = V_{IH}$ or V_{IL} $I_{OL} = 2 \text{ mA}$ $I_{OL} = 2.6 \text{ mA}$ | 4.5 6.0 | - - | 0.17 0.18 | 0.26 0.26 | - - | 0.33 0.33 | - - | 0.40 0.40 | |
| I _{IN} | Input Leakage Current | V _{IN} = 6.0 V or GND | 6.0 | _ | _ | ±0.1 | - | ±1.0 | - | ±1.0 | μΑ |
| I _{CC} | Quiescent Supply Current | V _{IN} = V _{CC} or GND | 6.0 | _ | _ | 1.0 | - | 10 | - | 40 | μА |

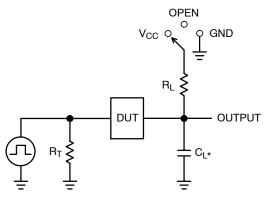
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS

| | | | Т | T _A = 25°C | | -40° C \leq T _A \leq 85 $^{\circ}$ C -55 | | -55°C ≤ T | -55°C ≤ T _A ≤ 125°C | |
|--|---------------------------|---|-------------|-----------------------|-----------------------|--|-----------------------|-------------|--------------------------------|------|
| Symbol | Parameter | Test Conditions | Min | Тур | Max | Min | Max | Min | Max | Unit |
| t _{PLH} , | Propagation Delay, | V _{CC} = 5.0 V C _L = 15 pF | - | 3.5 | 15 | - | 20 | - | 25 | ns |
| ^t PHL | A to Y | $\begin{array}{cccccccccccccccccccccccccccccccccccc$ | | 20 11 8 7 | 100 27 20 17 | | 125 35 25 21 | | 155 90 35 26 | |
| t _{TLH} , t _{THL} | Output Transition Time | $V_{CC} = 5.0 \text{ V}$ $C_L = 15 \text{ pF}$ | - | 3 | 10 | - | 15 | - | 20 | ns |
| *IHL | | $ \begin{array}{llllllllllllllllllllllllllllllllllll$ | - - - | 25 16 11 9 | 125 35 25 21 | - - - | 155 45 31 26 | - - - | 200 60 38 32 | |
| C _{IN} | Input Capacitance | | - | 5 | 10 | - | 10 | - | 10 | pF |

| | | Typical @ 25°C, V _{CC} = 5.0 V | |
|----------|--|---|----|
| C_{PD} | Power Dissipation Capacitance (Note 4) | 10 | pF |

^{4.} C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no–load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.



| Test | Switch Position | C _L , pF | R _L , Ω |
|--|--------------------|------------------------------|--------------------|
| t _{PLH} / t _{PHL} | Open | | Х |
| t _{TLH} / t _{THL} (Note 5) | Open | See AC Characteristics Table | Х |
| t _{PLZ} / t _{PZL} | V _{CC} | lable | 1 k |
| t _{PHZ} / t _{PZH} | GND | | 1 k |

X - Don't Care

* C_L includes probe and jig capacitance R_T is Z_{OUT} of pulse generator (typically 50 W) f = 1 MHz

Figure 3. Test Circuit

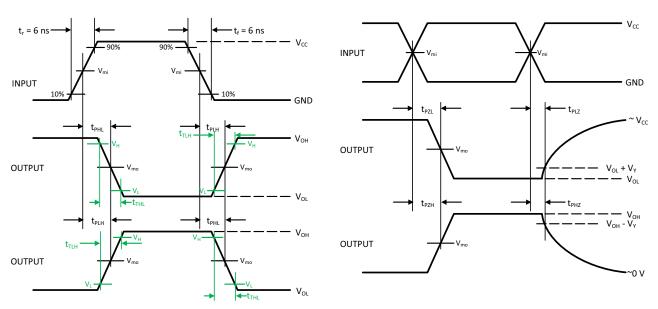


Figure 4. Switching Waveforms

| | | V _{mo} , V | | | | |
|---------------------|---------------------|-------------------------------------|--------------------------------------|--|--|--------------------|
| V _{CC} , V | V _{mi} , V | t _{PLH} , t _{PHL} | $t_{PZL}, t_{PLZ}, t_{PZH}, t_{PHZ}$ | V_L, V | V _H , V | V _Y , V |
| 3.0 to 3.6 | V _{CC} /2 | V _{CC} /2 | V _{CC} /2 | V _{OL} + 0.1 (V _{OH} – V _{OL}) | V _{OL} + 0.9 (V _{OH} – V _{OL}) | 0.3 |
| 4.5 to 5.5 | V _{CC} /2 | V _{CC} /2 | V _{CC} /2 | V _{OL} + 0.1 (V _{OH} – V _{OL}) | V _{OL} + 0.9 (V _{OH} – V _{OL}) | 0.3 |

^{5.} t_{TLH} and t_{THL} are measured from 10% to 90% of ($V_{OH} - V_{OL}$), and 90% to 10% of ($V_{OH} - V_{OL}$), respectively.

ORDERING INFORMATION

| Device | Packages | Specific Device Code | Pin 1 Orientation (See below) | Shipping [†] |
|---|----------|----------------------|----------------------------------|-----------------------|
| MC74HC1G04DFT1G | SC-88A | H5 | Q2 | 3000 / Tape & Reel |
| MC74HC1G04DFT1G-Q* (Please contact onsemi) | SC-88A | H5 | Q2 | 3000 / Tape & Reel |
| MC74HC1G04DFT2G | SC-88A | H5 | Q4 | 3000 / Tape & Reel |
| MC74HC1G04DFT2G-Q* (Please contact onsemi) | SC-88A | H5 | Q4 | 3000 / Tape & Reel |
| MC74HC1G04DBVT1G | SC-74A | H5 | Q4 | 3000 / Tape & Reel |

[†]For complete information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Pin 1 Orientation in Tape and Reel

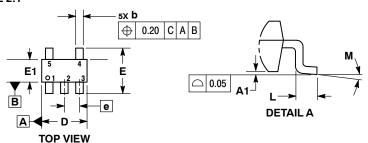
Direction of Feed

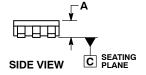


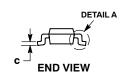
^{*-}Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.



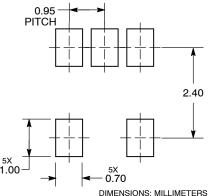
DATE 18 JAN 2018











*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NOTES:

- IES:
 DIMENSIONING AND TOLERANCING PER ASME
 Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH
 THICKNESS. MINIMUM LEAD THICKNESS IS THE
 MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE.

| | MILLIMETERS | | | | |
|-----|-------------|------|--|--|--|
| DIM | MIN | MAX | | | |
| Α | 0.90 | 1.10 | | | |
| A1 | 0.01 | 0.10 | | | |
| b | 0.25 | 0.50 | | | |
| С | 0.10 | 0.26 | | | |
| D | 2.85 | 3.15 | | | |
| E | 2.50 | 3.00 | | | |
| E1 | 1.35 | 1.65 | | | |
| е | 0.95 BSC | | | | |
| L | 0.20 | 0.60 | | | |
| М | 0° | 10° | | | |

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

Μ = Date Code = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ", may or may not be present. Some products may not follow the Generic Marking.

| DOCUMENT NUMBER: | 98AON66279G | Electronic versions are uncontrolled except when accessed directly from the Docume Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in re- | | |
|------------------|-------------|--|-------------|--|
| DESCRIPTION: | SC-74A | | PAGE 1 OF 1 | |

ON Semiconductor and unare trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.





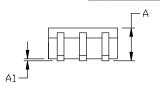
SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE M

DATE 11 APR 2023

NOTES:

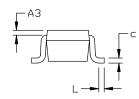
- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. 419A-01 DBSDLETE, NEW STANDARD 419A-02
- 4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH,
 PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS,
 OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

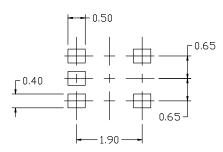
| DIM | MILLIMETERS | | |
|-----|-------------|------|------|
| | MIN. | N□M. | MAX. |
| А | 0.80 | 0.95 | 1.10 |
| A1 | | | 0.10 |
| A3 | 0,20 REF | | |
| b | 0.10 | 0.20 | 0.30 |
| C | 0.10 | | 0.25 |
| D | 1.80 | 2.00 | 2,20 |
| Е | 2.00 | 2.10 | 2.20 |
| E1 | 1.15 | 1.25 | 1.35 |
| е | 0.65 BSC | | |
| L | 0.10 | 0.15 | 0.30 |



5X b

◆ 0.2 M B M





RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

GENERIC MARKING DIAGRAM*



*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

| STYLE 1: |
|-----------------------------|
| PIN 1. BASE |
| EMITTER |
| 3. BASE |
| COLLECTOR |
| COLLECTOR |
| |

STYLE 2:
PIN 1. ANODE
2. EMITTER
3. BASE
4. COLLECTOR
5. CATHODE

STYLE 3: PIN 1. ANODE 1 2. IV/C 3. ANODE 2 4. CATHODE 2 5. CATHODE 1 STYLE 4:
PIN 1. SOURCE 1
2. DRAIN 1/2
3. SOURCE 1
4. GATE 1
5. GATE 2

STYLE 5:
PIN 1. CATHODE
2. COMMON ANODE
3. CATHODE 2
4. CATHODE 3
5. CATHODE 4

STYLE 6: PIN 1. EMITTER 2 2. BASE 2 3. EMITTER 1 4. COLLECTOR STYLE 7:
PIN 1. BASE
2. EMITTER
3. BASE
4. COLLECTOR
5. COLLECTOR

STYLE 8: PIN 1. CATHODE 2. COLLECTOR 3. N/C 4. BASE 5. EMITTER STYLE 9: PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE 5. ANODE Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

DOCUMENT NUMBER:

98ASB42984B

Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.

DESCRIPTION: SC-88A (SC-70-5/SOT-353)

PAGE 1 OF 1

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

5. COLLECTOR 2/BASE 1

onsemi, Onsemi, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. Onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA class 3 medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

www.onsemi.com/support/sales